

FEATURES

- Overshoot and Undershoot Voltage Protection
- Specified Break-Before-Make Switching
- Low ON-State Resistance (10 Ω)
- Control Inputs Are 5-V Tolerant
- Low Charge Injection
- Excellent ON-Resistance Matching
- Low Total Harmonic Distortion (THD)
- 1.8-V to 5.5-V Single-Supply Operation
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Performance Tested Per JESD 22
 - 2000-V Human-Body Model (A114-B, Class II)
 - 1000-V Charged-Device Model (C101)
 - 300-V Machine Model (A115-A)

APPLICATIONS

- Sample-and-Hold Circuit
- Battery-Powered Equipments
- Audio and Video Signal Routing
- Communication Circuits

DESCRIPTION/ORDERING INFORMATION

The TS5A623157 is a dual single-pole, double-throw (SPDT) analog switch designed to operate from 1.65 V to 5.5 V. This device can handle both digital and analog signals. Signals up to V+ (peak) can be transmitted in either direction.

The TS5A623157 senses overshoot and undershoot events at the I/Os and responds by preventing voltage differentials from developing and turning the switch on.

ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾	(2)	ORDERABLE PART NUMBER	TOP-SIDE MARKING	
–40°C to 85°C	VSSOP (MSOP-10) - DGS	Tape and reel	TS5A623157DGSR	35R	
-40 C 10 85 C	QFN – RSE	Tape and reel	TS5A623157RSER	PREVIEW	

(1) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

(2) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

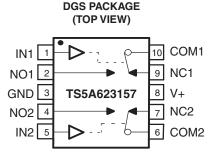
IN	NC TO COM, COM TO NC	NO TO COM, COM TO NO									
L	ON	OFF									
н	OFF	ON									

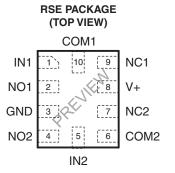
FUNCTION TABLE



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

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SUMMARY OF CHARACTERISTICS $V_{\perp} = 5 V, T_{\Delta} = 25^{\circ}C$

Configuration	2:1 multiplexer/demultiplexer (1 \times SPDT)
Number of channels	2
ON-state resistance (r _{on})	10 Ω
ON-state resistance match (Δr_{on})	0.15 Ω
ON-state resistance flatness (r _{on(flat)})	2 Ω
Turn-on/turn-off time (t _{ON} /t _{OFF})	5 ns / 3.4 ns
Break-before-make time (t _{BBM})	0.5 ns
Charge injection (Q _C)	5 pC
Bandwidth (BW)	371 MHz
OFF isolation (O _{ISO})	–61 dB at 10 MHz
Crosstalk (X _{TALK})	–61 dB at 10 MHz
Total harmonic distortion (THD)	0.06%
Leakage current (I _{NO(OFF)} /I _{NC(OFF)})	±1 µA
Power-supply current (I ₊)	1.2 µA
Undershoot protection	-2 V
Overshoot protection	V ₊ + 2 V
Package options	10-pin VSSOP (DGS), 10-pin QFN (RSE)

Absolute Minimum and Maximum Ratings⁽¹⁾⁽²⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V+	Supply voltage range ⁽³⁾		-0.5	6.5	V
V _{NC} V _{NO} V _{COM}	Analog voltage range ⁽³⁾⁽⁴⁾⁽⁵⁾		-0.5	V ₊ + 0.5	V
I _{I/OK}	Analog port diode current	$V+ < V_{NC}, V_{NO}, V_{COM} < 0$		±50	mA
I _{NC} I _{NO} I _{COM}	On-state switch current	V_{NC} , V_{NO} , $V_{COM} = 0$ to V+		±50	mA
V _{IN}	Digital input voltage range ⁽³⁾⁽⁴⁾		-0.5	6.5	V
I _{IK}	Digital input clamp current	V ₁ < 0		-50	mA
l+ I _{GND}	Continuous current through V ₊ or GND			±100	mA
T _{stg}	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The algebraic convention, whereby the most negative value is a minimum and the most positive value is a maximum. (2)

(3) All voltages are with respect to ground, unless otherwise specified.

(4) (5) The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

This value is limited to 5.5 V maximum.

Package Thermal Impedance

				UNIT
٥	Package thermal impedance ⁽¹⁾	DGS package	°C/W	
θ_{JA}		RSE package	243	C/W

(1) The package thermal impedance is calculated in accordance with JESD 51-7.



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Electrical Characteristics for 5-V Supply

 $V_{+} = 4.5 \text{ V}$ to 5.5 V, $T_{A} = -40^{\circ}\text{C}$ to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST COND	ITIONS	TA	V.	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V _{COM} , V _{NO} , V _{NC}					0		V+	V
Voltage undershoot	V _{IKU}	$0 \geq (I_{NC}, I_{NO}, or I_{COM}) \geq$	–50 mA		5.5 V			-2	V
Peak ON-state	r .	$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$	Switch ON,	25°C	4.5 V		4.6	11	Ω
resistance	r _{peak}	$I_{COM} = -30 \text{ mA},$	See Figure 14	Full	4.5 V			13	12
		V_{NO} or $V_{NC} = 0$,		25°C			4	6.5	
		$I_{COM} = 30 \text{ mA}$		Full				8	
ON-state	r	V_{NO} or $V_{NC} = 2.4 V$,	Switch ON,	25°C	4.5 V		4	8	Ω
resistance	r _{on}	$I_{COM} = -30 \text{ mA}$	See Figure 14	Full	4.5 V			10	
		$V_{NO} \text{ or } V_{NC} = 4.5 \text{ V},$		25°C	_		5.5	10	
		$I_{COM} = -30 \text{ mA}$		Full				12	
ON-state				25°C			0.1	0.14	Ω
resistance match between channels	∆r _{on}	V_{NO} or V_{NC} = 3.15 V, I_{COM} = -30 mA,	Switch ON, See Figure 14	Full	4.5 V			0.15	
ON-state		$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$	Switch ON,	25°C			1.5	2	
resistance flatness	r _{on(flat)}	$I_{COM} = -30 \text{ mA},$	See Figure 14	Full	4.5 V			4	Ω
NC, NO	I _{NC(OFF)} ,	V_{NC} or $V_{NO} = 0$ to V_+ ,	Switch OFF,	25°C			1	20	
OFF leakage current	I _{NO(OFF)}	$V_{COM} = V_+$ to 0	See Figure 15	Full	5.5 V			150	nA
NC, NO	I _{NC(ON)} ,	V_{NC} or $V_{NO} = 0$ to V_+ ,	Switch ON,	25°C			1	20	
ON leakage current	I _{NO(ON)}	$V_{COM} = Open,$	See Figure 16	Full	5.5 V			150	nA
СОМ		V_{NC} or V_{NO} = Open,	Switch ON,	25°C			1	20	
ON leakage current	I _{COM(ON)}	$V_{COM} = 0$ to V_+ ,	See Figure 16	Full	5.5 V			150	nA
Digital Control I	nput (IN)								
Input logic high	V _{IH}			Full		$V_{+} \times 0.7$		5.5	V
Input logic low	VIL			Full		0		$V_{\text{+}} \times 0.3$	V
Input leakage		$V_1 = 5.5 V \text{ or } 0$		25°C	5.5 V		0.1	10	nA
current	I _{IH} , I _{IL}	vj = 3.5 v 01 0		Full	5.5 V			30	TIA.



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Electrical Characteristics for 5-V Supply (continued)

 V_{+} = 4.5 V to 5.5 V, T_{A} = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CON	DITIONS	T _A	۷.	MIN	TYP	MAX	UNIT
Dynamic									
				25°C	5 V	1	3.5	5	
Turn-on time	t _{ON}	$\label{eq:V_COM} \begin{array}{l} V_{COM} = V_{+} \text{ or GND}, \\ R_{L} = 500 \ \Omega, \end{array}$	C _L = 50 pF, See Figure 17	Full	4.5 V to 5.5 V	1		6	ns
			0 50 - 5	25°C	5 V	1	2.8	3.4	
Turn-off time	t _{OFF}	$\label{eq:V_COM} \begin{array}{l} V_{COM} = V_{+} \text{ or GND}, \\ R_{L} = 500 \ \Omega, \end{array}$	C _L = 50 pF, See Figure 17	Full	4.5 V to 5.5 V	1		3.8	ns
Output voltage during undershoot	V _{OUTU}	See Figure 24				2.5	V _{OH} – 0.3		V
Output voltage during overshoot	V _{оито}	See Figure 24					V _{OL} + 0.3	2	v
Break-before-		$V_{\rm NC} = V_{\rm NO} = V_{+}/2,$	$C_1 = 50 \text{ pF},$	25°C	5 V	0.5	5	12	
make time	t _{BBM}	$v_{\rm NC} = v_{\rm NO} = v_{\pm}/2,$ R _L = 50 Ω,	See Figure 18	Full	4.5 V to 5.5 V	0.5		14	ns
Charge injection	Q _C	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C _L = 0.1 nF, See Figure 22	25°C	5 V		110		рС
NC, NO OFF capacitance	C _{NC(OFF)} , C _{NO(OFF)}	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch OFF,	See Figure 16	25°C	5 V		5		pF
NC, NO ON capacitance	C _{NC(ON)} , C _{NO(ON)}	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch ON,	See Figure 16	25°C	5 V		14.5		pF
COM ON capacitance	C _{COM(ON)}	$V_{COM} = V_+ \text{ or GND},$ Switch ON,	See Figure 16	25°C	5 V		14.5		pF
Digital input capacitance	Cı	$V_I = V_+ \text{ or } GND,$	See Figure 16	25°C	5 V		3.5		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON,	See Figure 19	25°C	5 V		371		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega,$ f = 10 MHz,	Switch OFF, See Figure 20	25°C	5 V		-61		dB
Crosstalk	X _{TALK}	$\begin{array}{l} R_{L}=50\ \Omega,\\ f=10\ MHz, \end{array}$	Switch ON, See Figure 21	25°C	5 V		-61		dB
Total harmonic distortion	THD	$ \begin{array}{l} R_L = 600 \; \Omega, \\ C_L = 50 \; pF, \end{array} $	f = 20 Hz to 20 kHz, See Figure 23	25°C	5 V		0.06		%
Supply		·							
Positive supply	I+	$V_{I} = V_{+}$ or GND,	Switch ON or	25°C	5.5 V		0.01	0.15	μA
current	'+		OFF	Full	5.5 v			1.2	μΛ



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Electrical Characteristics for 3.3-V Supply

V₊ = 3 V to 3.6 V, T_A = -40° C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST COND	ITIONS	TA	V.	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V _{COM} , V _{NO} , V _{NC}					0		V ₊	V
Voltage undershoot	V _{IKU}	$0 \geq (I_{NC}, I_{NO}, or I_{COM}) \geq$	–50 mA		3.6 V				V
Peak ON-state resistance	r _{peak}	$\begin{array}{l} 0 \leq (V_{NO} \text{ or } V_{NC}) \leq V_{+}, \\ I_{COM} = -24 \text{ mA}, \end{array}$	Switch ON, See Figure 14	25°C Full	3 V		8.9	14 18	Ω
ON-state		V_{NO} or $V_{NC} = 0$, $I_{COM} = 24 \text{ mA}$	Switch ON.	25°C Full			5.4	8	
resistance	r _{on}	$V_{NO} \text{ or } V_{NC} = 3 \text{ V},$ $I_{COM} = -24 \text{ mA}$	See Figure 14	25°C Full	3 V		7.4	12	Ω
ON-state resistance match between	Δr _{on}	V_{NO} or V_{NC} = 2.1 V, I_{COM} = -24 mA,	Switch ON, See Figure 14	25°C Full	3 V		0.1	0.2	Ω
channels ON-state resistance flatness	r _{on(flat)}	$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$ $I_{COM} = -24 \text{ mA},$	Switch ON, See Figure 14	25°C Full	3 V		2.8	4	Ω
NC, NO OFF leakage current	I _{NC(OFF)} , I _{NO(OFF)}	V_{NC} or $V_{NO} = 0$ to V_+ , $V_{COM} = V_+$ to 0	Switch OFF, See Figure 15	25°C Full	3.6 V		0.5	10 100	nA
NC, NO ON leakage current	I _{NC(ON)} , I _{NO(ON)}	V_{NC} or $V_{NO} = 0$ to V_+ , $V_{COM} = Open$,	Switch ON, See Figure 16	25°C Full	3.6 V		0.5	10 100	nA
COM ON leakage current	I _{COM(ON)}	V_{NC} or V_{NO} = Open, V_{COM} = 0 to V_{+} ,	Switch ON, See Figure 16	25°C Full	3.6 V		0.5	10 100	nA
Digital Control I	nput (IN)								
Input logic high	V _{IH}			Full		$V_{+} \times 0.7$		5.5	V
Input logic low	V _{IL}			Full		0		$V_{+} imes 0.3$	V
Input leakage current	I _{IH} , I _{IL}	V _I = 5.5 V or 0		25°C Full	3.6 V		0.1	10 20	nA



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Electrical Characteristics for 3.3-V Supply (continued)

 V_{\star} = 3 V to 3.6 V, T_{A} = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CON	DITIONS	TA	۷,	MIN	TYP	MAX	UNIT
Dynamic				- #					
				25°C	3.3 V	1	4.7	9.0	
Turn-on time	t _{ON}	$V_{COM} = V_+ \text{ or GND},$ $R_L = 500 \Omega,$	C _L = 50 pF, See Figure 17	Full	3 V to 3.6 V	1		10.0	ns
			0 50 55	25°C	3.3 V	1	3.2	6.3	
Turn-off time	t _{OFF}	$\label{eq:V_COM} \begin{array}{l} V_{COM} = V_{+} \text{ or GND}, \\ R_{L} = 500 \ \Omega, \end{array}$	C _L = 50 pF, See Figure 17	Full	3 V to 3.6 V	1		7.0	ns
Output voltage during undershoot	V _{OUTU}	See Figure 24				2.5	V _{OH} – 0.3		V
Output voltage during overshoot	V _{OUTO}	See Figure 24					V _{OL} + 0.3	2	V
Break-before-		$V_{\rm NC} = V_{\rm NO} = V_{\rm +}/2,$	C _L = 50 pF,	25°C	3.3 V	0.5	7	17	
make time	t _{BBM}	$R_{\rm L} = 50 \ \Omega,$	See Figure 18	Full	3 V to 3.6 V	0.5		19.5	ns
Charge injection	Q _C	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C _L = 0.1 nF, See Figure 22	25°C	3.3 V		75		рС
NC, NO OFF capacitance	$\begin{array}{c} C_{NC(OFF)},\\ C_{NO(OFF)} \end{array}$	V_{NC} or $V_{NO} = V_+$ or GND, Switch OFF,	See Figure 16	25°C	3.3 V		5		pF
NC, NO ON capacitance	C _{NC(ON)} , C _{NO(ON)}	V_{NC} or $V_{NO} = V_+$ or GND, Switch ON,	See Figure 16	25°C	3.3 V		14.5		pF
COM ON capacitance	C _{COM(ON)}	$V_{COM} = V_+ \text{ or GND},$ Switch ON,	See Figure 16	25°C	3.3 V		14.5		pF
Digital input capacitance	CI	$V_1 = V_+ \text{ or GND},$	See Figure 16	25°C	3.3 V		3.5		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON,	See Figure 19	25°C	3.3 V		370		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega$, f = 10 MHz,	Switch OFF, See Figure 20	25°C	3.3 V		-60		dB
Crosstalk	X _{TALK}	$R_L = 50 \Omega$, f = 10 MHz,	Switch ON, See Figure 21	25°C	3.3 V		-60		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 23	25°C	3.3 V		0.1		%
Supply									
Positive supply current	I+	$V_1 = V_+ \text{ or GND},$	Switch ON or OFF	25°C Full	3.6 V		0.05	0.5 0.75	μA



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Electrical Characteristics for 2.5-V Supply

 V_{+} = 2.3 V to 2.7 V, T_{A} = -40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CONI	DITIONS	TA	۷,	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V _{COM} , V _{NO} , V _{NC}					0		V ₊	V
Voltage undershoot	V _{IKU}	0 mA ≥ (I_{NC} , I_{NO} , or I_{CO}	_M) ≥ <i>−</i> 50 mA		2.7 V				V
Peak ON-state	r	$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$	Switch ON,	25°C	2.3 V		13.9	30	Ω
resistance	r _{peak}	$I_{COM} = -8 \text{ mA},$	See Figure 14	Full	2.3 V			35	12
		V_{NO} or $V_{NC} = 0$,		25°C	-		6.6	8.5	
ON-state	r _{on}	I _{COM} = 8 mA	Switch ON,	Full	2.3 V			12	Ω
resistance	on	V_{NO} or V_{NC} = 2.3 V,	See Figure 14	25°C	2.0 V		8.9	18	32
		$I_{COM} = -8 \text{ mA}$		Full				25	
ON-state resistance				25°C	-		0.05	0.3	
match between channels	Δr_{on}	V_{NO} or V_{NC} = 1.6 V, I_{COM} = -8 mA,	Switch ON, See Figure 14	Full	2.3 V			0.5	Ω
ON-state		$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$	Switch ON.	25°C			5	15	
resistance flatness	r _{on(flat)}	$I_{COM} = -8 \text{ mA},$	See Figure 14	Full	2.3 V			20	Ω
NC, NO	I _{NC(OFF)} ,	V_{NC} or $V_{NO} = 0$ to V_{+} ,	Switch OFF,	25°C	0.7.1		0.1	10	
OFF leakage current	I _{NO(OFF)}	$V_{COM} = V_+$ to 0,	See Figure 15	Full	2.7 V			100	nA
NC, NO	I _{NC(ON)} ,	V_{NC} or $V_{NO} = 0$ to V_+ ,	Switch ON,	25°C			0.1	10	
ON leakage current	I _{NO(ON)}	V _{COM} = Open,	See Figure 16	Full	2.7 V			10	nA
СОМ		V_{NC} or V_{NO} = Open,	Switch ON.	25°C			0.1	10	
ON leakage current	I _{COM(ON)}	$V_{COM} = 0$ to V_+ ,	See Figure 16	Full	2.7 V			100	nA
Digital Control	Input (IN)								
Input logic high	V _{IH}			Full		$V_{+} imes 0.75$		5.5	V
Input logic low	V _{IL}			Full		0		$V_{+} imes 0.25$	V
Input leakage	կ _H , կլ	$V_1 = 5.5 V \text{ or } 0$		25°C	2.7 V		5	10	nA
current	ıH, ıL	vi = 0.0 v 0i 0		Full	2.1 V			20	



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Electrical Characteristics for 2.5-V Supply (continued)

 V_{+} = 2.3 V to 2.7 V, T_{A} = –40°C to 85°C (unless otherwise noted)

SYMBOL	TEST COM	NDITIONS	TA	V ₊	MIN	TYP	MAX	UNIT
			25°C	2.5 V	2	6.2	9.6	
t _{ON}	$v_{COM} = v_+ \text{ or GND},$ $R_L = 500 \Omega,$	C _L = 50 pF, See Figure 17	Full	2.3 V to 2.7 V	2		12	ns
		0 50 - 5	25°C	2.5 V	1.5	4.5	7.0	
t _{OFF}	$v_{COM} = v_+ \text{ or GND},$ $R_L = 500 \Omega,$	C _L = 50 pF, See Figure 17	Full	2.3 V to 2.7 V	1.5		7.5	ns
V _{OUTU}	See Figure 24					V _{OH} – 0.3		V
V _{OUTO}	See Figure 24					V _{OL} + 0.3	2	V
	$V_{\rm exp} = V_{\rm exp} = V_{\rm e}/2$	$C_{\rm c} = 50 \rm pE$	25°C	2.5 V	0.5	10	25	
t _{BBM}	$R_{\rm L} = 50 \ \Omega,$	See Figure 18	Full	2.3 V to 2.7 V	0.5		28.5	ns
Q_{C}	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C _L = 0.1 nF, See Figure 22	25°C	2.5 V		58		рС
C _{NC(OFF)} , C _{NO(OFF)}	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch OFF,	See Figure 16	25°C	2.5 V		5		pF
C _{NC(ON)} , C _{NO(ON)}	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch ON,	See Figure 16	25°C	2.5 V		14.5		pF
C _{COM(ON)}	$V_{COM} = V_+ \text{ or GND},$ Switch ON,	See Figure 16	25°C	2.5 V		14.5		pF
CI	$V_I = V_+ \text{ or GND},$	See Figure 16	25°C	2.5 V		3.5		pF
BW	$R_L = 50 \Omega$, Switch ON,	See Figure 19	25°C	2.5 V		367		MHz
O _{ISO}	$R_L = 50 \Omega$, f = 10 MHz,	Switch OFF, See Figure 20	25°C	2.5 V		-60		dB
X _{TALK}	$R_L = 50 \Omega,$ f = 10 MHz,	Switch ON, See Figure 21	25°C	2.5 V		-60		dB
THD	$ \begin{array}{l} R_{L} = 600 \ \Omega, \\ C_{L} = 50 \ pF, \end{array} $	f = 20 Hz to 20 kHz, See Figure 23	25°C	2.5 V		0.15		%
				.				
l+	$V_I = V_+ \text{ or } GND,$	Switch ON or OFF	25°C Full	2.7 V		50	100 550	nA
	t _{ON} t _{OFF} V _{OUTU} V _{OUTU} t _{BBM} Q _C C _{NC(OFF)} , C _{NC(ON)} , C _{NO(ON)} C _{COM(ON)} C _{COM(ON)} C _I BW O _{ISO} X _{TALK} THD	t_{ON} $V_{COM} = V_+ \text{ or GND}, R_L = 500 \Omega,$ t_{OFF} $V_{COM} = V_+ \text{ or GND}, R_L = 500 \Omega,$ V_{OUTU} See Figure 24 V_{OUTO} See Figure 24 t_{BBM} $V_{NC} = V_{NO} = V_+/2, R_L = 50 \Omega,$ Q_C $V_{GEN} = 0, R_{GEN} = 0,$ Q_C $V_{NC} \text{ or } V_{NO} = V_+ \text{ or } O, R_{GEN} = 0,$ $C_{NC(OFF)}, C_{NO(OFF)}$ $V_{NC} \text{ or } V_{NO} = V_+ \text{ or } O, Switch OFF,$ $C_{NC(ON)}, C_{NO(ON)}$ $V_{COM} = V_+ \text{ or } GND, Switch ON,$ $C_{COM(ON)}$ $V_{COM} = V_+ \text{ or } GND, Switch ON,$ C_{I} $V_I = V_+ \text{ or } GND,$ BW $R_L = 50 \Omega, f = 10 \text{ MHz},$ X_{TALK} $R_L = 600 \Omega, C_L = 50 \text{ pF},$	ton $V_{COM} = V_+ \text{ or GND}, R_L = 500 \Omega,$ $C_L = 50 \text{ pF}, \text{ See Figure 17}$ toFF $V_{COM} = V_+ \text{ or GND}, R_L = 500 \Omega,$ $C_L = 50 \text{ pF}, \text{ See Figure 17}$ V_{OUTU} See Figure 24 V_{OUTO} See Figure 24 V_{OUTO} See Figure 24 $C_L = 50 \text{ pF}, \text{ See Figure 18}$ Q_{OUTO} See Figure 0, R_L = 50 \Omega, See Figure 18 $C_L = 0.1 \text{ nF}, \text{ See Figure 22}$ Q_C $V_{GEN} = 0, \text{ See Figure 22}$ $C_L = 0.1 \text{ nF}, \text{ See Figure 22}$ $C_{NC(OFF)}, C_{NO(OFF)}$ $V_{NC} \text{ or } V_{NO} = V_+ \text{ or } \text{ See Figure 16}$ See Figure 16 $C_{NO(OFF)}$ $V_{NC} \text{ or } V_{NO} = V_+ \text{ or } \text{ GND}, \text{ See Figure 16}$ See Figure 16 $C_{COM(ON)}$ $V_{COM} = V_+ \text{ or GND}, \text{ See Figure 16}$ Switch ON, See Figure 16 BW $R_L = 50 \Omega, \text{ Switch ON}, \text{ See Figure 19}$ Switch ON, See Figure 20 X_{TALK} $R_L = 50 \Omega, \text{ Switch ON}, \text{ See Figure 21}$ THD $R_L = 600 \Omega, \text{ C}_L = 50 \text{ PF}, \text{ See Figure 23}$	ton $V_{COM} = V_{+} \text{ or GND}, R_{L} = 50 \text{ pF}, See Figure 17 \frac{25^{\circ}C}{Full} toFF V_{COM} = V_{+} \text{ or GND}, R_{L} = 50 \text{ pF}, See Figure 17 \frac{25^{\circ}C}{Full} V_{OUTU} See Figure 24 T_{UIII} V_{OUTU} See Figure 24 T_{UIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIIII$	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	$\begin{array}{c c c c c c c c c c c c c c c c c c c $



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Electrical Characteristics for 1.8-V Supply

V₊ = 1.65 V to 1.95 V, T_A = -40° C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST COND	DITIONS	TA	V+	MIN	TYP	MAX	UNIT
Analog Switch									
Analog signal range	V _{COM} , V _{NO} , V _{NC}					0		V ₊	V
Voltage undershoot	V _{IKU}	$0 \ge (I_{NC}, I_{NO}, \text{ or } I_{COM}) \ge$: −50 mA		1.95 V				V
Peak		$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$	Switch ON	25°C			41.1	60	
ON-state resistance	r _{peak}	$I_{COM} = -4 \text{ mA},$	See Figure 14	Full	1.65 V			120	Ω
		V_{NO} or $V_{NC} = 0$,		25°C	_		9.2	15	
ON-state	r _{on}	$I_{COM} = 4 \text{ mA}$	Switch ON,	Full	1.65 V			15	Ω
resistance	'on	V_{NO} or V_{NC} = 1.65 V,	See Figure 14	25°C	1.00 V		1.8	40	32
		$I_{COM} = -4 \text{ mA}$		Full				45	
ON-state				25°C	_		0.1	0.6	I
resistance match between channels	Δr_{on}	V_{NO} or V_{NC} = 1.15 V, I_{COM} = -4 mA,	Switch ON, See Figure 14	Full 1.65 V			0.8	Ω	
ON-state		$0 \le (V_{NO} \text{ or } V_{NC}) \le V_+,$	Switch ON	25°C			26.5	80	
resistance flatness	r _{on(flat)}	$I_{COM} = -4 \text{ mA},$	See Figure 14	Full	1.65 V			100	Ω
NC, NO	I _{NC(OFF)} ,	V_{NC} or $V_{NO} = 0$ to V_{+}	Switch OFF,	25°C			0.05	10	
OFF leakage current	I _{NO(OFF)}	$V_{\rm COM} = V_+ \text{ to } 0,$	See Figure 15	Full	1.95 V			100	nA
NC, NO	I _{NC(ON)} ,	V_{NC} or $V_{NO} = 0$ to V_+ ,	Switch ON,	25°C			0.1	10	
ON leakage current	I _{NO(ON)}	$V_{COM} = Open,$	See Figure 16	Full	1.95 V			100	μA
COM		V _{NC} or V _{NO} = Open,	Switch ON,	25°C			0.1	10	
ON leakage current	I _{COM(ON)}	$V_{COM} = 0$ to V_+ ,	See Figure 16	Full 1.95 V			100	nA	
Digital Control In	nput (IN)								
Input logic high	VIH			Full		$V_{+} imes 0.75$		5.5	V
Input logic low	V _{IL}			Full		0		$V_{\text{+}} \times 0.25$	V
Input leakage current	I _{IH} , I _{IL}	V _I = 5.5 V or 0		25°C Full	1.95 V		0.05	1 20	nA

PRODUCT PREVIEW



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Electrical Characteristics for 1.8-V Supply (continued)

 V_{+} = 1.65 V to 1.95 V, T_{A} = –40°C to 85°C (unless otherwise noted)

PARAMETER	SYMBOL	TEST CON	V.	MIN	TYP	MAX	UNIT		
Dynamic									
				25°C	1.8 V		9.6	23	
Turn-on time	t _{ON}	$V_{COM} = V_{+} \text{ or GND},$ $R_{L} = 500 \ \Omega,$	$C_L = 50 \text{ pF},$ See Figure 17	Full	1.65 V to 1.95 V			24	ns
				25°C	1.8 V		6.3	10	
Turn-off time	t _{OFF}	$V_{COM} = V_{+} \text{ or GND},$ $R_{L} = 500 \Omega,$	C _L = 50 pF, See Figure 17	Full	1.65 V to 1.95 V			12	ns
Output voltage during undershoot	V _{OUTU}	See Figure 24					V _{OH} – 0.3		V
Output voltage during overshoot	V _{OUTO}	See Figure 24					V _{OL} + 0.3		V
				25°C	1.8 V	0.5	18	50	
Break-before- make time	t _{BBM}	$\label{eq:VNC} \begin{split} V_{\text{NC}} &= V_{\text{NO}} = V_{\text{+}}/2, \\ R_{\text{L}} &= 50 \ \Omega, \end{split}$	C _L = 50 pF, See Figure 18	Full	1.65 V to 1.95 V	0.5		55	ns
Charge injection	Q _C	$V_{GEN} = 0,$ $R_{GEN} = 0,$	C _L = 0.1 nF, See Figure 22	25°C	1.8 V		40		рС
NC, NO OFF capacitance	C _{NC(OFF)} , C _{NO(OFF)}	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch OFF,	See Figure 16	25°C	1.8 V		5.0		pF
NC, NO ON capacitance	C _{NC(ON)} , C _{NO(ON)}	V_{NC} or $V_{NO} = V_{+}$ or GND, Switch ON,	See Figure 16	25°C	1.8 V		14.5		pF
COM ON capacitance	C _{COM(ON)}	V _{COM} = V ₊ or GND, Switch ON,	See Figure 16	25°C	1.8 V		14.5		pF
Digital input capacitance	CI	$V_I = V_+ \text{ or } GND,$	See Figure 16	25°C	1.8 V		3.5		pF
Bandwidth	BW	$R_L = 50 \Omega$, Switch ON,	See Figure 19	25°C	1.8 V		369		MHz
OFF isolation	O _{ISO}	$R_L = 50 \Omega$, f = 10 MHz,	Switch OFF, See Figure 20	25°C	1.8 V		-60		dB
Crosstalk	X _{TALK}	$R_L = 50 \Omega,$ f = 10 MHz,	Switch ON, See Figure 21	25°C	1.8 V		-60		dB
Total harmonic distortion	THD	$R_L = 600 \Omega,$ $C_L = 50 pF,$	f = 20 Hz to 20 kHz, See Figure 23	25°C	1.8 V		0.4		%
Supply									
Positive supply current	I+	$V_1 = V_+ \text{ or GND},$	Switch ON or OFF	25°C Full	1.95 V		0.1	50 400	nA

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PIN DESCRIPTION

PIN NO.	NAME	DESCRIPTION
1	IN1	Digital control to connect COM to NO or NC
2	NO1	Normally open
3	GND	Digital ground
4	NO2	Normally open
5	IN2	Digital control to connect COM to NO or NC
6	COM2	Common
7	NC2	Normally closed
8	V+	Power supply
9	NC1	Normally closed
10	COM1	Common

PARAMETER DESCRIPTION

SYMBOL	DESCRIPTION								
V _{COM}	Voltage at COM								
V _{NC}	Voltage at NC								
V _{NO}	Voltage at NO								
r _{on}	Resistance between COM and NC or COM and NO ports when the channel is ON								
∆r _{on}	Difference of r _{on} between channels								
r _{on(flat)}	Difference between the maximum and minimum value of ron in a channel over the specified range of conditions								
I _{NC(OFF)}	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the OFF state under worst-case input and output conditions								
I _{NO(OFF)}	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the OFF state under worst-case input and output conditions								
I _{NC(ON)}	Leakage current measured at the NC port, with the corresponding channel (NC to COM) in the ON state and the output (COM) being open								
I _{NO(ON)}	Leakage current measured at the NO port, with the corresponding channel (NO to COM) in the ON state and the output (COM) being open								
I _{COM(ON)}	Leakage current measured at the COM port, with the corresponding channel (NO to COM or NC to COM) in the ON state and the output (NC or NO) being open								
V _{IH}	Minimum input voltage for logic high for the control input (IN)								
V _{IL}	Minimum input voltage for logic low for the control input (IN)								
V _{IN}	Voltage at control input (IN)								
I _{IH} , I _{IL}	Leakage current measured at control input (IN)								
t _{ON}	Turn-on time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog outputs (COM/NC/NO) signal when the switch is turning ON.								
t _{OFF}	Turn-off time for the switch. This parameter is measured under the specified range of conditions and by the propagation delay between the digital control (IN) signal and analog outputs (COM/NC/NO) signal when the switch is turning OFF.								
t _{BBM}	Break-before-make time. This parameter is measured under the specified range of conditions and by the propagation delay between the output of two adjacent analog channels (NC and NO) when the control signal changes state.								
Q _C	Charge injection is a measurement of unwanted signal coupling from the control (IN) input to the analog (NC, NO, or COM) output. This is measured in coulombs =) and measured by the total charge induced due to switching of the control input. Charge injection, $Q_c = C_L \times \Delta V_O$, C_L is the load capacitance and ΔV_O is the change in analog output voltage.								
C _{NC(OFF)}	Capacitance at the NC port when the corresponding channel (NC to COM) is OFF								
C _{NO(OFF)}	Capacitance at the NO port when the corresponding channel (NC to COM) is OFF								
C _{NC(ON)}	Capacitance at the NC port when the corresponding channel (NC to COM) is ON								
C _{NO(ON)}	Capacitance at the NO port when the corresponding channel (NC to COM) is ON								
C _{COM(ON)}	Capacitance at the COM port when the corresponding channel (COM to NC or COM to NO) is ON								
CI	Capacitance of control input (IN)								
O _{ISO}	OFF isolation of the switch is a measurement of OFF-state switch impedance. This is measured in dB in a specific frequency, with the corresponding channel (NC to COM or NO to COM) in the OFF state.								



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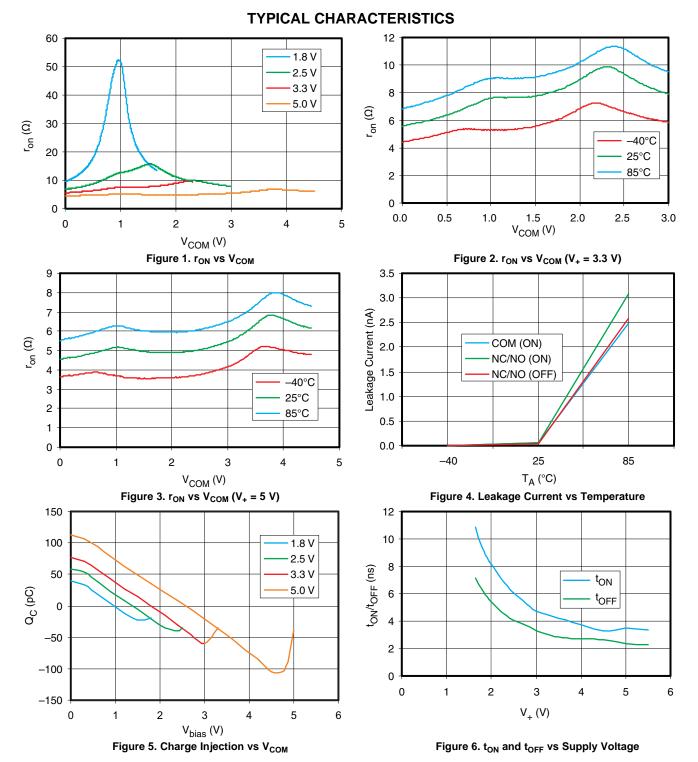
PARAMETER DESCRIPTION (continued)

SYMBOL	DESCRIPTION Crosstalk is a measurement of unwanted signal coupling from an ON channel to an OFF channel (NC to NO or NO to NC). This is measured at a specific frequency and in dB.							
X _{TALK}								
BW	Bandwidth of the switch. This is the frequency where the gain of an ON channel is -3 dB below the dc gain.							
THD	Total harmonic distortion is defined as the ratio of the root mean square (RMS) value of the second, third, and higher harmonics to the magnitude of fundamental harmonic.							
l+	Static power-supply current with the control (IN) pin at V+ or GND							
V _{OUTU}	Output voltage during an undershoot event. This is measured by turning off a specific channel and applying an undershoot voltage at the input of the switch.							
V _{OUTO}	Output voltage during an overshoot event. This is measured by turning off a specific channel and applying an overshoot voltage at the input of the switch.							

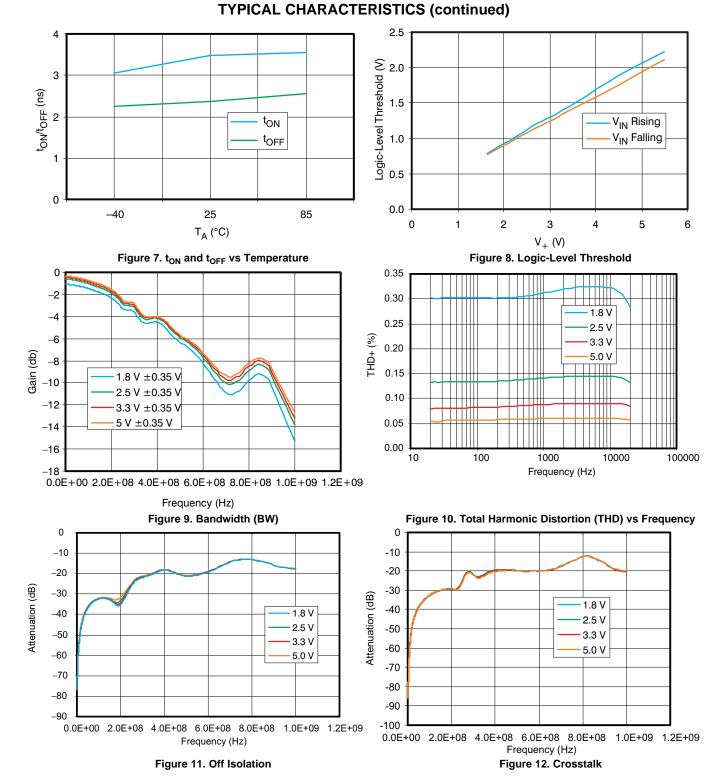


TS5A623157 DUAL 10-Ω SPDT ANALOG SWITCH WITH UNDERSHOOT/OVERSHOOT VOLTAGE PROTECTION

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IEXAS

RUMENTS

TYPICAL CHARACTERISTICS (continued)

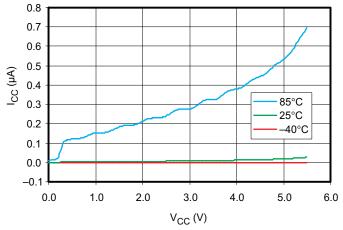
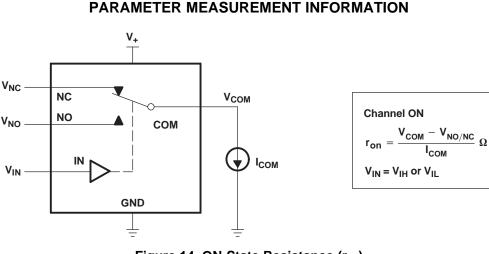


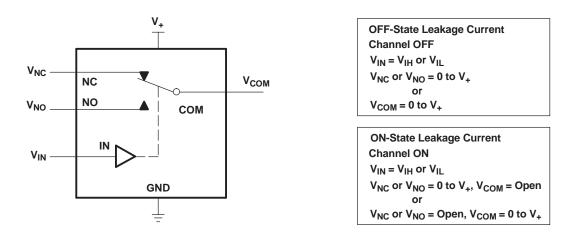
Figure 13. Supply Current vs Supply Voltage



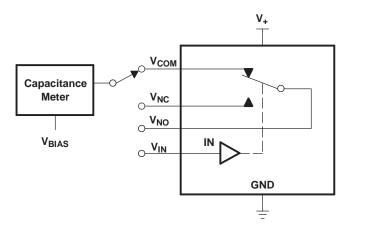
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 $V_{BIAS} = V_{+}$ or GND $V_{IN} = V_{IH}$ or V_{IL} Capacitance is measured at NC, NO, COM, and IN inputs during

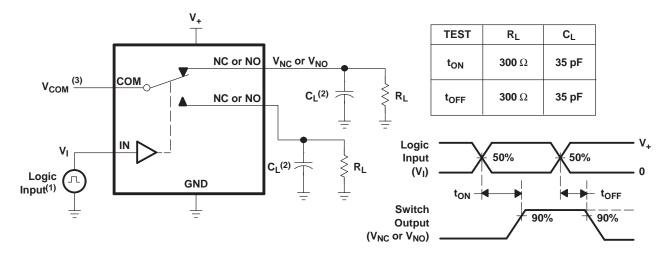
NO, COM, and IN inputs during ON and OFF conditions.





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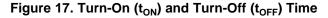
PARAMETER MEASUREMENT INFORMATION (continued)



⁽¹⁾ All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z₀ = 50 Ω , t_f < 5 ns, t_f < 5 ns.

⁽²⁾ C_L includes probe and jig capacitance.

 $^{(3)}$ See Electrical Characteristic for V_{COM}.



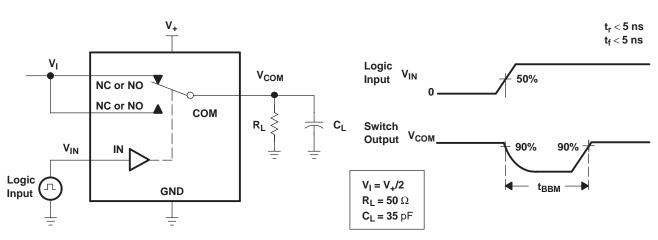
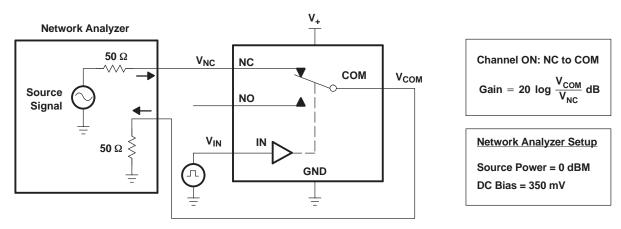


Figure 18. Break-Before-Make (t_{BBM}) Time







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PARAMETER MEASUREMENT INFORMATION (continued)

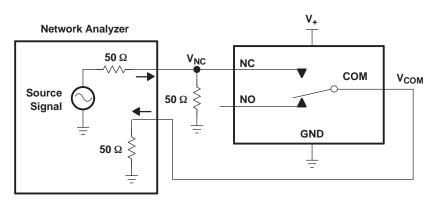
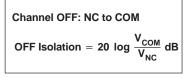
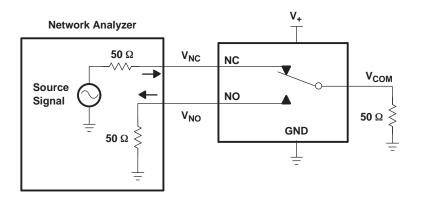


Figure 20. OFF Isolation (O_{ISO})



Network Analyzer Setup Source Power = 0 dBM DC Bias = 350 mV



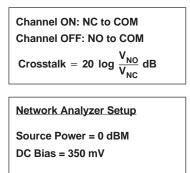
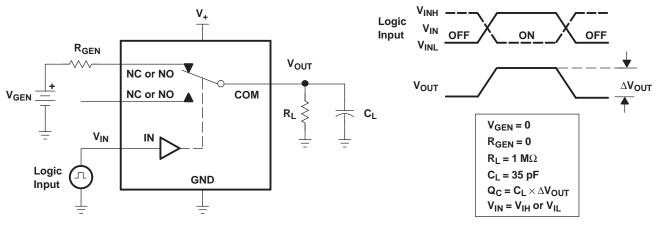


Figure 21. Crosstalk (X_{TALK)}







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PARAMETER MEASUREMENT INFORMATION (continued)

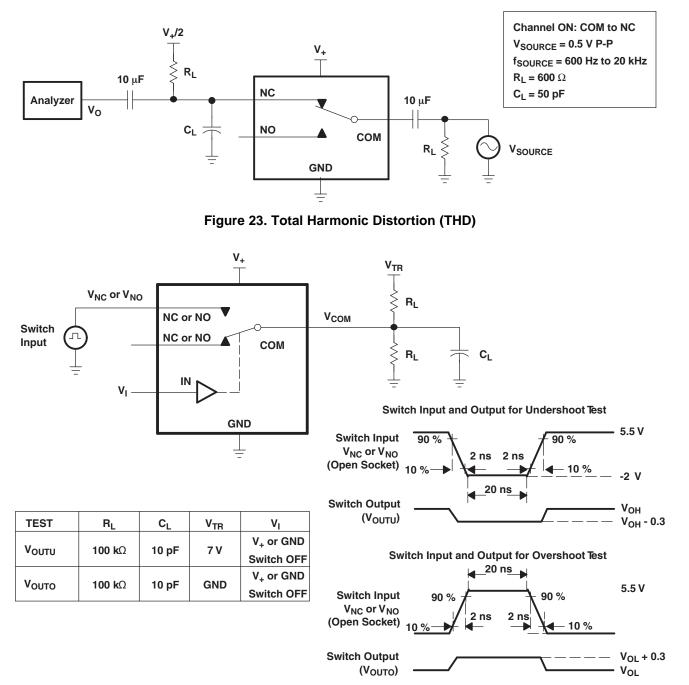


Figure 24. Undershoot and Overshoot Test



PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TS5A623157DGSR	Active	Production	VSSOP (DGS) 10	2500 LARGE T&R	Yes	NIPDAU SN	Level-1-260C-UNLIM	-40 to 85	35R
TS5A623157DGSR.B	Active	Production	VSSOP (DGS) 10	2500 LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 85	35R

⁽¹⁾ **Status:** For more details on status, see our product life cycle.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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Texas

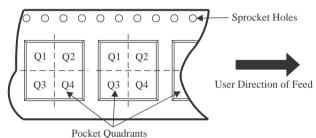
STRUMENTS

TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	-	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TS5A623157DGSR	VSSOP	DGS	10	2500	330.0	12.4	5.25	3.35	1.25	8.0	12.0	Q1
TS5A623157DGSR	VSSOP	DGS	10	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1



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PACKAGE MATERIALS INFORMATION

5-Nov-2024



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TS5A623157DGSR	VSSOP	DGS	10	2500	366.0	364.0	50.0
TS5A623157DGSR	VSSOP	DGS	10	2500	358.0	335.0	35.0

DGS0010A



PACKAGE OUTLINE

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-187, variation BA.



DGS0010A

EXAMPLE BOARD LAYOUT

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



DGS0010A

EXAMPLE STENCIL DESIGN

VSSOP - 1.1 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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